

Qualification Test Plan

MIL-STD-461





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	H/W	System	Testing

	Version History					
Document Release	Date	Change Item	Remarks			
V1.0	07/28/2025	Preliminary release				

	System Configuration
Motherboard	Supermicro X13SEW-TF
CPU	Intel® Xeon SP Gold 5411N (1.9Ghz, 165W, 45MB)
PCH	Intel C741 Chipset
RAM1	Samsung DDR5 5600 64GB RDIMM ECC
RAM2	Samsung DDR5 5600 64GB RDIMM ECC
RAM3	Samsung DDR5 5600 64GB RDIMM ECC
RAM4	Samsung DDR5 5600 64GB RDIMM ECC
RAM5	Samsung DDR5 5600 64GB RDIMM ECC
RAM6	Samsung DDR5 5600 64GB RDIMM ECC
RAM7	Samsung DDR5 5600 64GB RDIMM ECC
RAM8	Samsung DDR5 5600 64GB RDIMM ECC
GPU	Nvidia Tesla L4 24GB GDDR6 7680 CUDA Cores
SATA 1	2.5" U.2 NVMe 8TB SSD PCIe Gen III x 4
SATA 2	2.5" U.2 NVMe 8TB SSD PCIe Gen III x 4
LAN 1	Intel® 10 Gigabit X550 Ethernet
LAN 2	Intel® 10 Gigabit X550 Ethernet
LAN3	Intel® 1 Gigabit i350 Ethernet
IPMI	1 GbE Dedicated IPMI LAN port
USB	4 x USB 2.0
VGA	VGA D-Sub Connector port (Aspeed AST2600 BMC)
POWER	DC-DC 18V to 36V (500W Max) MIL-STD-461
Dimension	450(D) x 316 (W) x 154 (H) mm
Weight	18Kg(39.68lbs)
Chassis	Aluminum Alloy, Corrosion Resistant
Finish	Anodic aluminum oxide
Cooling	Natural Passive convection/Conduction with IP65 Active Smart Fans
Ingress Protection	IP65

System Reliability/Environment Test table of Content

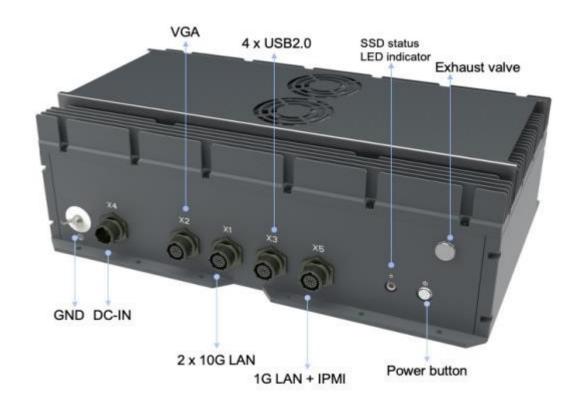
1	AVR	R800-S4L4 D38999 CONNECTORS AND ICD	4
2	I/O F	FUNCTIONAL TESTS	8
3	STR	ESS CPU/GPU TEST	14
4		DER OF TESTS AND USAGE OF TEST UNITS	
+			
	4-1	TEST UNITS	
	4-2	ESS AND BONDING	
	4-3	ORDER OF TESTS	16
5	MIL	-STD-461 TESTS	17
	5-1	RE102 TEST	18
	5-1.1	Requirements	18
	5-1.2	Test Procedure	18
	5-1.3	Test Configuration	19
	5-2	RS103 TEST	21
	5-2.1	Requirements	21
	5-2.2	Test Procedure	21
	5-2.3	Test Configuration	22
	5-3	CE102 TEST.	25
	5-3.1	Requirements	25
	5-3.2	Test Procedure	25
	5-3.3	Test Configuration	25
	5-4	CS101 TEST.	27
	5-4.1	Requirements	27
	5-4.2	Test Procedure	28
	5-4.3	Test Configuration	29
	5-5	CS114 TEST	30
	5-5.1	Requirements	30
	5-5.2	Test Procedure	30
	5-5.3	Test Configuration	31
	5-5.4	Test Setup of wires in the DC In cable:	32
	5-6	CS115 TEST	33
	5-6.1	Requirements	33
	5-6.2	Test Procedure	33
	5-6.3	Test Configuration	34
	5-6.4	Test Setup of wires in the DC In cable:	35
	5-7	CS116 TEST	36

5-7.1	Requirements	36
5-7.2	Test Procedure	36
<i>5-7.3</i>	Test Configuration	38
5-8 C	5118 TEST	39
5-8.1	Requirements	39
5-8.2	Test Procedure	39

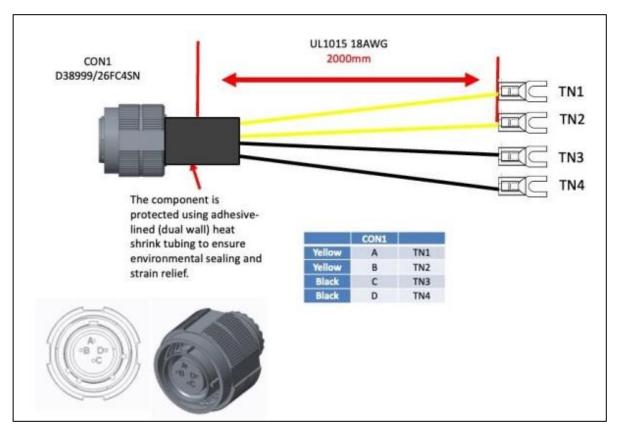
1 AVR800-S4L4 D38999 Connectors and ICD

INDEX

- A) X1 2 x 10G LAN (AMPHENOL TV07RW13-35SN)
- B) X2 VGA (AMPHENOL TV07RW-13-98S)
- C) X3 4 x USB 2.0 (AMPHENOL TV07RW13-35SB)
- D) X4 DC-IN (AMPHENOL TV07RW-13-04P)
- E) X5 1G LAN + IPMI (AMPHENOL TV07RW13-35SN)

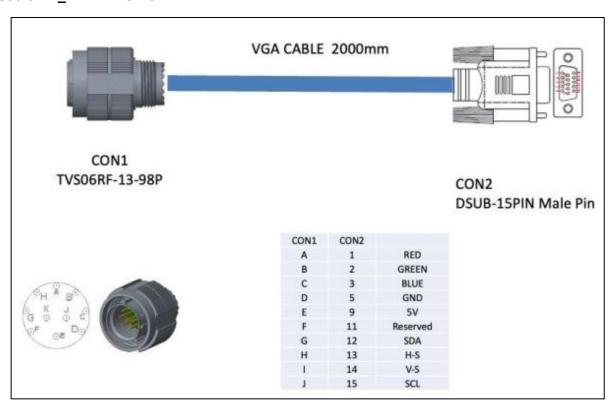


AV800-S4L4_1 EXT-DC-IN CABLE



Note: The DC In cable is unshielded

AV800-S4L4_11 EXT VGA CABLE



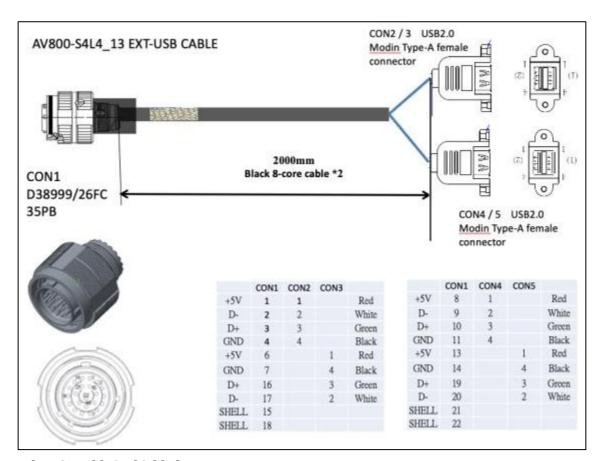
Note: The VGA cable is shielded

AV800-S4L4_15 EXT-10G LAN CABLE

CON1	CON2		CON1	CON3
1	1	WHITE / ORANGE	8	1
2	2	ORANG	9	2
3	3	WHITE / GREEN	10	3
4	6	GREEN	11	6
5	4	WHITE / BLUE	12	4
6	5	BLUE	13	5
15	7	WHITE / BROWN	19	7
16	8	BROWN	20	8

Note: The 10G LAN cable is shielded

AV800-S4L4_13 EXT-USB CABLE

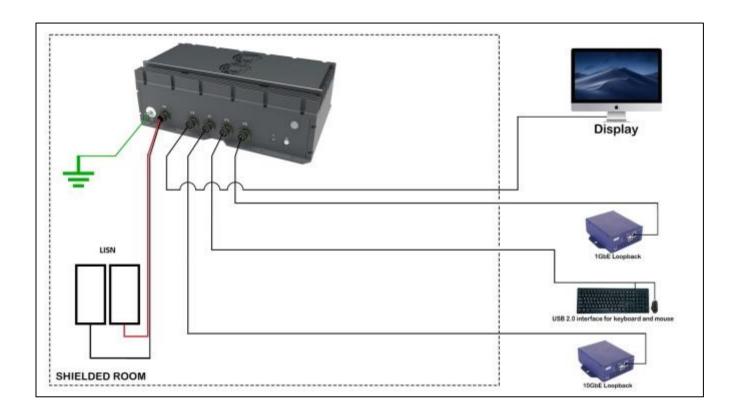


Note: The USB cable is shielded

AV800-S4L4_17 EXT-1G LAN CABLE

CON1	CON2		CON1	CON3
1	1	WHITE / ORANGE	8	1
2	2	ORANG	9	2
3	3	WHITE / GREEN	10	3
4	6	GREEN	11	6
5	4	WHITE / BLUE	12	4
6	5	BLUE	13	5
15	7	WHITE / BROWN	19	7
16	8	BROWN	20	8

Note: The 1G LAN cable is shielded



2 I/O Functional Tests

A) Power Button & LED/ X4 (DC-In)



Test Method:

Testing the motherboard after pressing the power button.

Make sure the System switches ON and the LED lights up. When the system is correctly connected to the DC input and receives a valid operating voltage within the 18–36V range. that nominal input voltage is 28VDC.

X1/X5 (1GbE / Dual 10GbE LAN)



Test Method:

Loopback the dual channels one to the other using external cable.

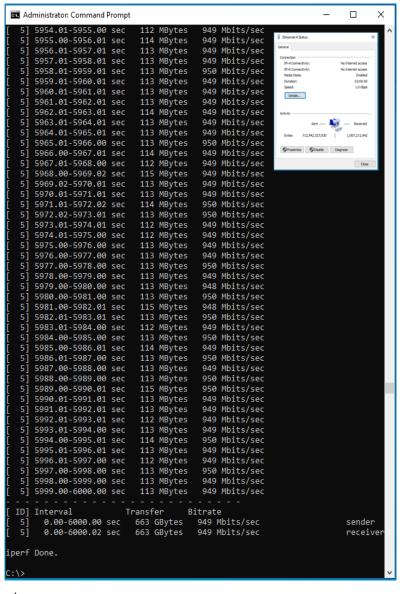
Check the LAN MAC ADDRESS on the MB, LAN SPEED and setup iPerf to test at 10GbE and 1GbE speeds.

X550 / i350 LAN

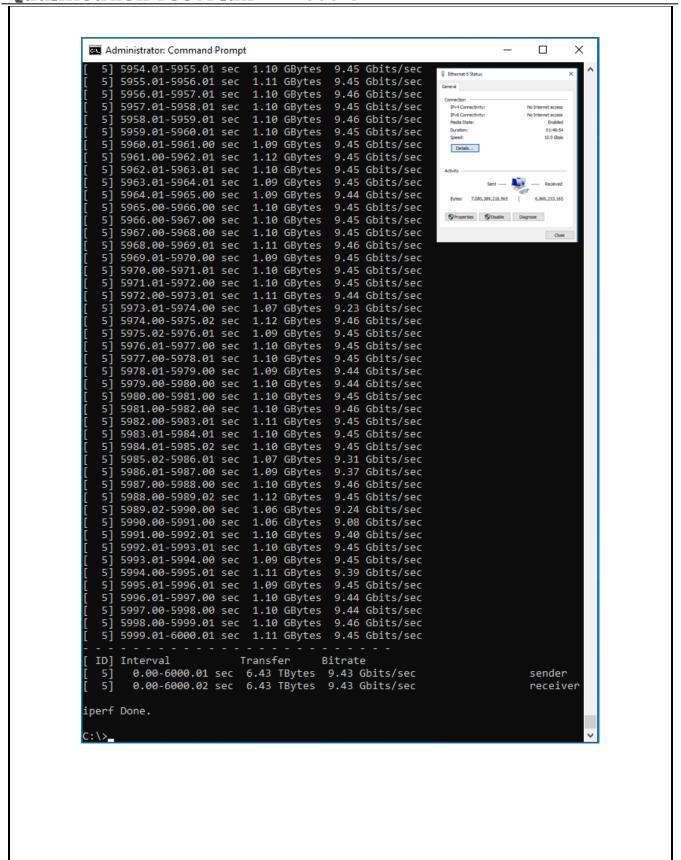
i350 1GE Connect them directly with a CAT5e/CAT6 cable or via a Gigabit switch. Ensure both NICs are set to 1 Gbps full-duplex and have valid IP addresses.

X550 10GE: NICs: Both endpoints must have 10GE adapters (SFP+, RJ45 10GBase-T, or QSFP breakout). Connect them directly with a CAT6A/CAT7 cable or via a Gigabit switch. Ensure both NICs are set to 10 Gbps full-duplex and have valid IP addresses.

iPerf 1GbE test speed



iPerf 10GbE test speed







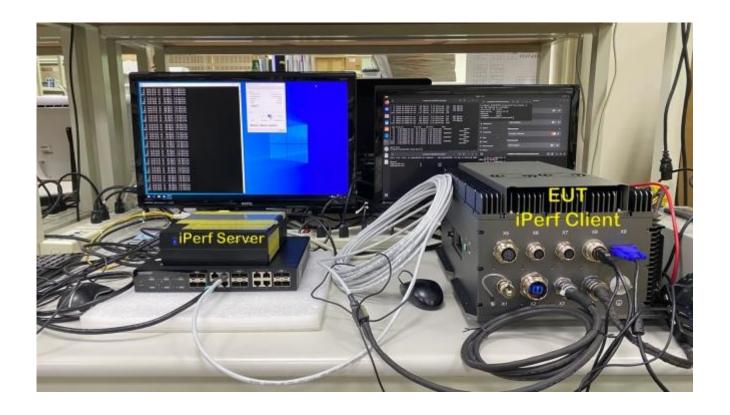
PC: A (iperf Server) IP: 192.168.1.4 Mask: 255.255.255.0 Gateway: 192.168.1.1

OS: Windows 10 64bits



PC: B (iperf Client) IP: 192.168.1.103 Mask: 255.255.255.0 Gateway: 192.168.1.1

OS: Windows 10 64bits



B) X2 (VGA)



Test Method:

Connect the VGA cable and make sure the screen will be displayed and the color is normal. functional. VGA is connected to an external screen for monitoring. Pass = clear picture. Fail= noise, flickering or loss of signal.

Pass = clear picture.



Fail= noise, flickering or loss of signal



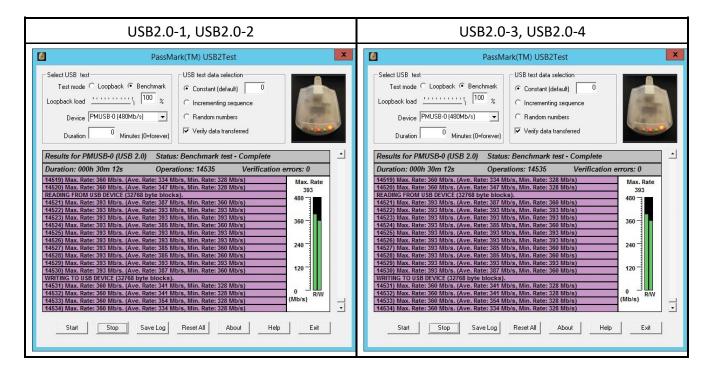
C) X3 (USB)



Test Method:

Check if we can detect the USB2.0 x4 with USB DEVICE TEST PLUG

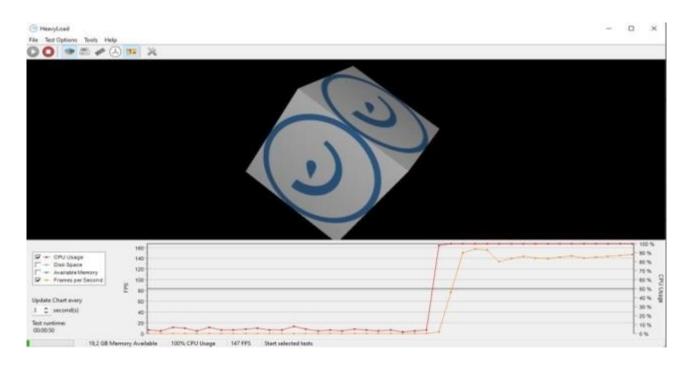
Loopback Plugs for USB 3.0 &USB2.0							
Software	Comment / (unit)	connector	Read / Write (Mb/s)	Result	Note		
		USB2.0-1	202/250/44//				
	PassMark USB2.0 test plug	USB2.0-2					
		USB2.0-3	393/360 (Mb/s)				
		USB2.0-4					



3 Stress CPU/GPU Test

HeavyLoad is intended to stress all resources of a PC (CPU, GPU, RAM, hard disk, network, operating system etc.) in order to test if it will run reliably under heavy load. This is useful for assessing important file or database servers before using them productively, or simply to ensure your new PC will not overheat or crash when used intensively.

The program also allows testing the behavior of systems under fading system resources (memory, disk space).



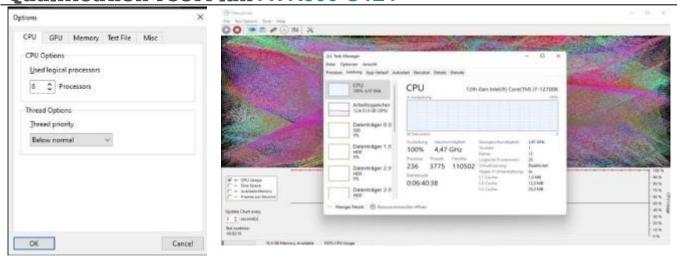
Stress CPU

Use your processor or even a specific number of processor cores to full capacity. HeavyLoad performs complex calculations to simulate the load on your processor. 0~100%

Allows to set the number of used logical processors for the CPU stress test if the system has more than one. The default number is set to the maximum amount of available processors (physical and virtual cores) on your system.

Thread Options Thread priority

Allows to define the priority at which the threads are running. This can be used to precisely control the system utilization of HeavyLoad. "Idle" means the CPU will only be used if no other threads are using it. Choosing a higher priority will result in the stress threads having a higher priority than the thread of the user interface, which may result in the user interface being unresponsive during the tests.



Stress GPU

HeavyLoad you can utilize your graphics card processor to capacity. HeavyLoad employs a 3D rendered graphic to simulate a high load on the GPU.



These tests will be run with StressCPU and StressGPU to load the AVR800-S4L4 to approximately 70% load on both the CPU and the GPU.

4 Order of tests and usage of test units

4-1 Test units

Two test units will be allocated for parallel testing activities: one unit for MIL-STD-461 compliance verification and the second unit for MIL-STD-810 environmental qualification testing.

4-2 ESS and bonding

Bonding will be tested on both units (less than 2.5 milliohm should be measured between X1/2/3/4/5 and the GND stud).

Both units should then undergo ESS, and have their bonding measured again. Record the results.

4-3 Order of Tests

The tests will be carried out on the single unit in the following order

- a) ESS/bonding.
- b) MIL-STD-461

5 MIL-STD-461 TESTS

REQUIREMENTS FOR THE CONTROL OF ELECTROMAGNETIC INTERFERENCE CHARACTERISTICS OF SUBSYSTEMS AND EQUIPMENT

The AVR800-S4L4 shall be tested under the ELECTROMAGNETIC INTERFERENCE CHARACTERISTICS as defined by MIL-STD-461G category: Ground, Army, as detailed according to the order in Table 1

Table 1: Order of Tests

#	Test					
		Spec' as Equipment Conditions				
1	RE102	Radiated emissions, electric filed, 2MHz to 18GHz (Figure RE102-4)				
2	RS103	Radiated susceptibility, electric filed, 2Mhz to 18GHz, 50V/m (2MHz to 100MHz: 50V/m 100MHz to 18GHz: 50V/m)				
3	CE102	Conducted emissions, power leads, 10KHz to 10MHz (Figure CE102-1)				
4	CS101	Conducted susceptibility, power leads, 30Hz to 150KHz (Figure CS101-1: Curve #2)				
5	CS114	Conducted susceptibility, bulk cable injection, 10KHz to 200MHz, curves 3&4 (10KHz to 2MHz, curves 3& 2MHz to 200MHz: Curve #4)				
6	CS115	Conducted susceptibility, bulk cable injection, impulse excitation (5A)				
7	CS116	Conducted susceptibility, damped sinusoidal transients, cables and power leads, 10KHz to 100MHz (10A)				
8	CS118	Personnel borne electrostatic discharge (Added upon the change from 461F to 461G)				

5-1 RE102 TEST

5-1.1 Requirements

Perform the Radiated emissions, electric field test in accordance with MIL-STD-461G the following parameters: **2MHz to 18GHz**

5-1.2 Test Procedure

<u>Limit</u>

Electric field emissions shall not be radiated in excess of those shown in Figures RE102-4. Above 30 MHz, the limits shall be met for both horizontally and vertically polarized fields according to Ground, Army curve.

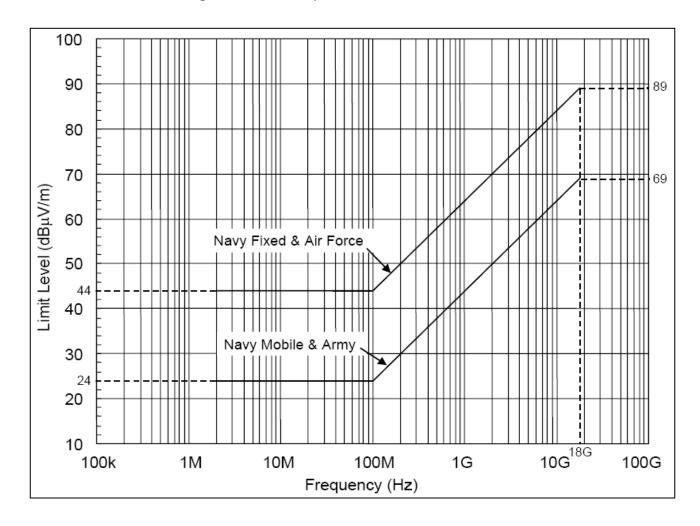
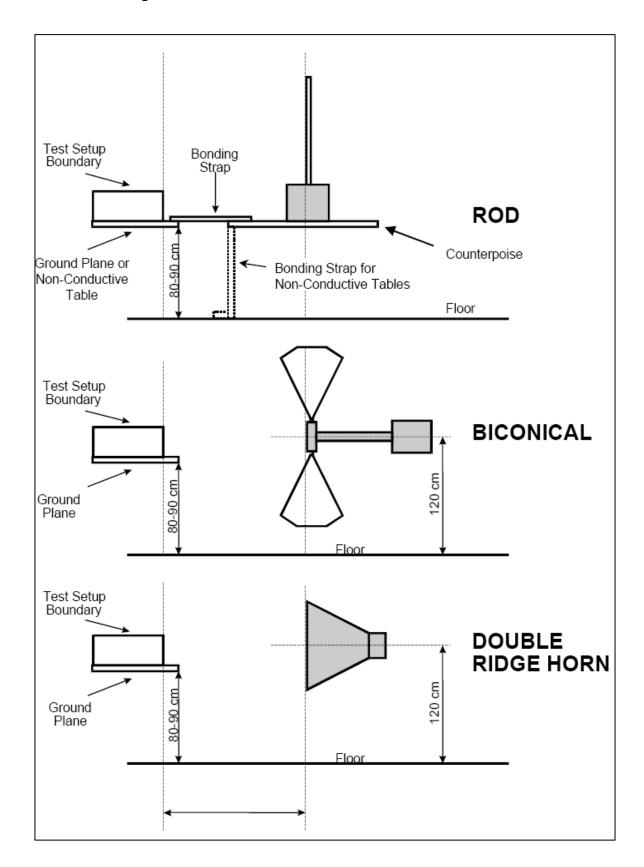
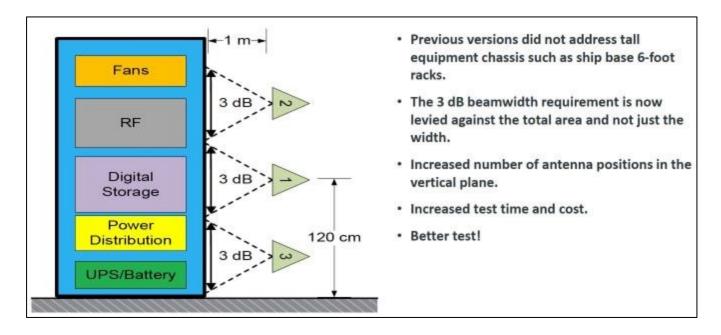


FIGURE RE102-4. RE102 limit for ground applications.

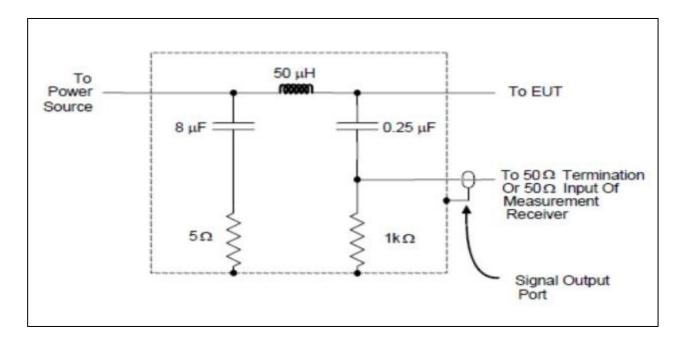
5-1.3 Test Configuration





The impedance of power sources providing input power to the EUT shall be controlled by Line Impedance Stabilization Networks (LISNs) for all measurement procedures of this document unless otherwise stated in a particular test procedure. LISNs shall not be used on output power leads. The LISNs shall be located at the power source end of the exposed length of power leads specified in 4.3.8.6.2.

• LISNs shall be electrically bonded to the test ground plane or facility ground as required and the bond resistance shall not exceed 2.5 milliohms.



5-2 RS103 TEST

5-2.1 Requirements

Perform the Radiated susceptibility, electric field test in accordance with MIL-STD-461G the following parameters: 2Mhz to 18GHz, 50V/m

5-2.2 Test Procedure

<u>Limit</u>

The EUT shall not exhibit any malfunction, degradation of performance, or deviation from. specified indications, beyond the tolerances indicated in the individual equipment or subsystem specification, when subjected to the radiated electric fields listed in Table VII and modulated as specified below. Up to 30 MHz, the requirement shall be met for vertically polarized fields. Above 30 MHz, the requirement shall be met for both horizontally and vertically polarized fields. Circular polarized fields are not acceptable.

			LIMIT LEVEL (VOLTS/METER)						
PLATE FREQ. RANGE	ORM	AIRCRAFT (EXTERNAL OR SAFETY CRITICAL)	AIRCRAFT INTERNAL	ALL SHIPS (ABOVE DECKS) AND SUBMARINES (EXTERNAL)*	SHIPS (METALLIC) (BELOW DECKS)	SHIPS (NON- METALLIC) (BELOW DECKS)	SUBMARINES (INTERNAL)	GROUND	SPACE
2 MHz	Α	200	200	200	10	50	5	50	20
↓	N	200	200	200	10	50	5	10	20
30 MHz	AF	200	20	,		-	-	10	20
30 MHz	A	200	200	200	10	10	10	50	20
	N	200	200	200	10	10	10	10	20
1 GHz	AF	200	20		,	-	,	10	20
1 GHz	A	200	200	200	10	10	10	50	20
↓	N	200	200	200	10	10	10	50	20
18 GHz	AF	200	60	,	,	-	,	50	20
18 GHz	A	200	200	200	10	10	10	50	20
↓	N	200	60	200	10	10	10	50	20
40 GHz	AF	200	60	-	-	-	-	50	20

KEY: A = Army N = Navy

AF = Air Force

Classification Of Functional Status

All classifications are for the total device/system functional status.

Class A: all functions of a device/system perform as designed during and after exposure to disturbance.

Class B: all functions of a device/system perform as designed during exposure. However, one or more of them can go beyond specified tolerance. All functions return automatically to within normal limits after exposure is removed.

Class C: one or more functions of a device/system do not perform as designed during exposure but return automatically to normal operation after exposure is removed.

Class D: one or more functions of a device/system do not perform as designed during exposure and do not return to normal operation until exposure is removed and the device/system is reset by simple "operator/use" action.

Class E: one or more functions of a device/system do not perform as designed during and after exposure and cannot be returned to proper operation without repairing or replacing the device/system.

For equipment located external to the pressure hull of a submarine but within the superstructure, use SHIPS (METALLIC)(BELOW DECKS)

5-2.3 Test Configuration

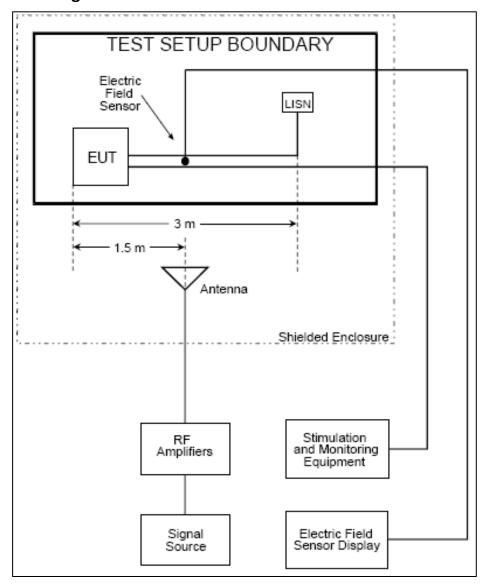


FIGURE RS103-1. Test equipment configuration.

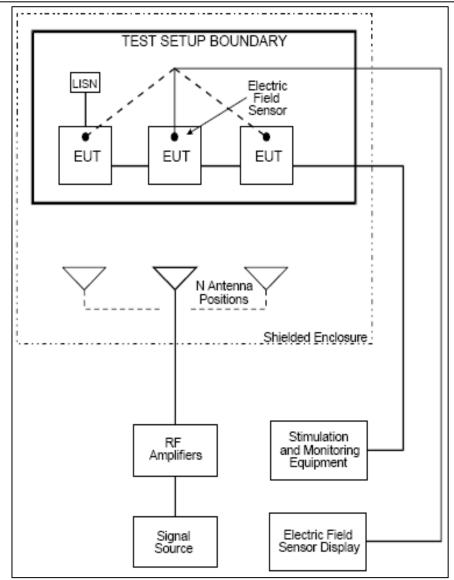


FIGURE RS103-2. Multiple test antenna locations for frequency > 200 MHz

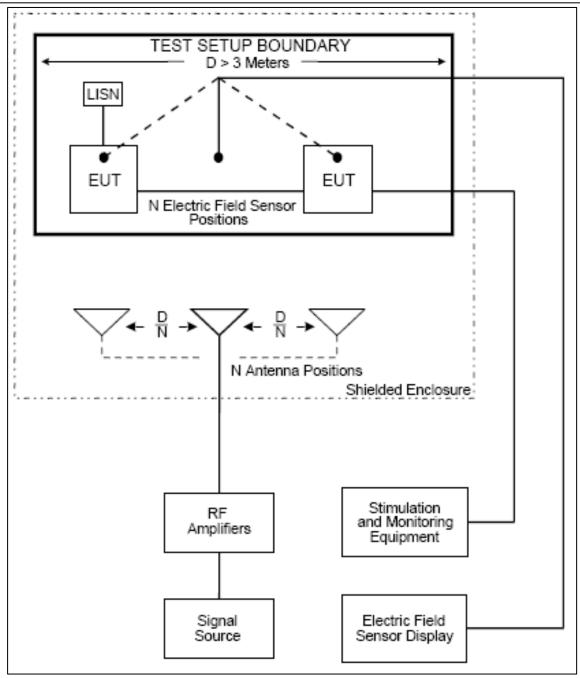


FIGURE RS103-3. Multiple test antenna locations for N positions, D > 3 meters

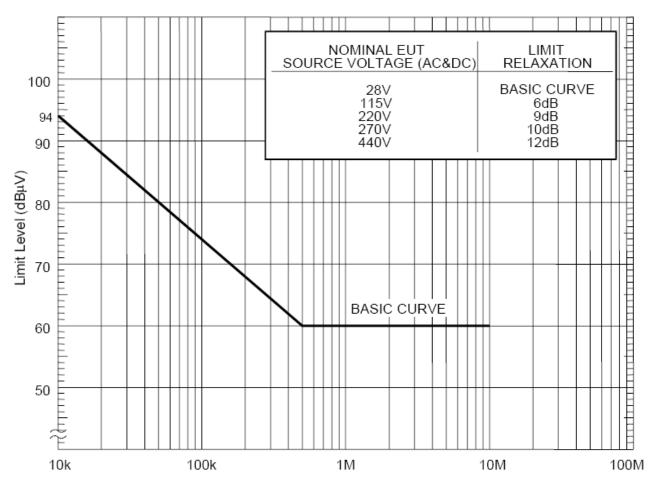
5-3 CE102 TEST

5-3.1 Requirements

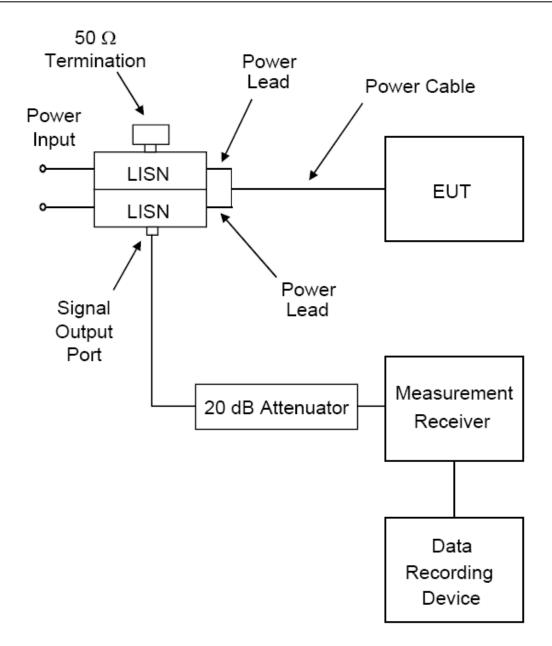
Perform the Conducted emissions, power leads test in accordance with MIL-STD-461G the following parameters:10KHz to 10MHz

5-3.2 Test Procedure

Conducted emissions on power leads shall not exceed the applicable values shown on Figure CE102-1.



5-3.3 Test Configuration



5-4 CS101 TEST

5-4.1 Requirements

Perform the Conducted susceptibility, power leads test in accordance with MIL-STD-461G the following parameters:**30Hz to 150KHz**

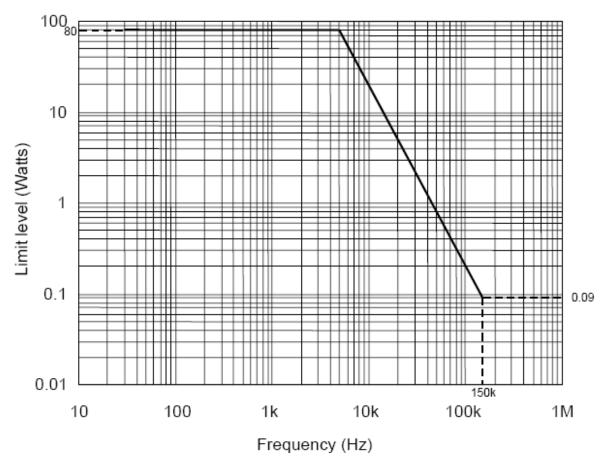


FIGURE CS101-2. CS101 power limit for all applications.

5-4.2 Test Procedure

Limit

The EUT shall not exhibit any malfunction, degradation of performance, or deviation from specified indications, beyond the tolerances indicated in the individual equipment or subsystem specification, when subjected to a test signal with voltage levels as specified in Figure CS101-1. The requirement is also met when the power source is adjusted to dissipate the power level shown in Figure CS101-2 in a 0.5 ohm load and the EUT is not susceptible.

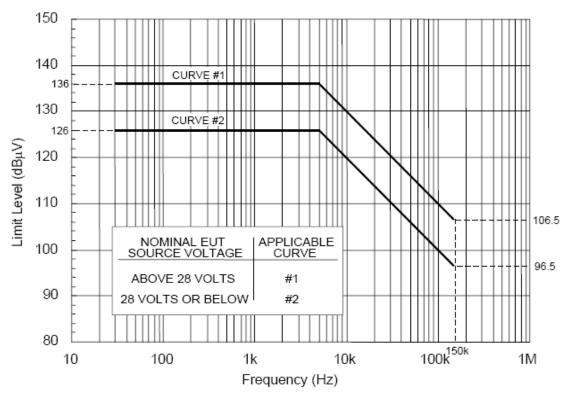


FIGURE CS101-1. CS101 voltage limit for all applications.

Classification Of Functional Status

All classifications are for the total device/system functional status.

Class A: all functions of a device/system perform as designed during and after exposure to disturbance.

Class B: all functions of a device/system perform as designed during exposure. However, one or more of them can go beyond specified tolerance. All functions return automatically to within normal limits after exposure is removed.

Class C: one or more functions of a device/system do not perform as designed during exposure but return automatically to normal operation after exposure is removed.

Class D: one or more functions of a device/system do not perform as designed during exposure and do not return to normal operation until exposure is removed and the device/system is reset by simple "operator/use" action.

Class E: one or more functions of a device/system do not perform as designed during and after exposure and cannot be returned to proper operation without repairing or replacing the device/system.

5-4.3 Test Configuration

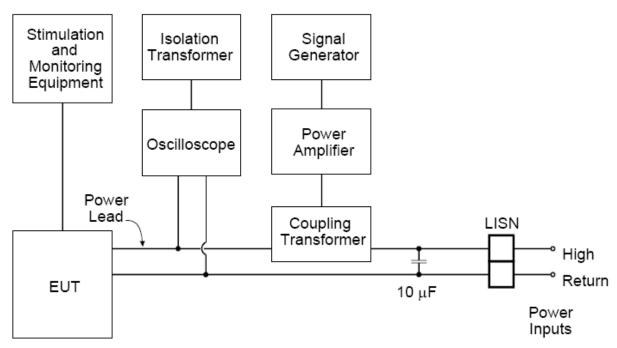


FIGURE CS101-4. Signal injection, DC or single phase AC

5-5 CS114 TEST

5-5.1 Requirements

Perform the Conducted susceptibility, bulk cable injection test in accordance with MIL-STD-461G the following parameters: **10 kHz to 2 MHz: Curve #3 ; 2MHz to 200MHz: Curve #4**

Limit

The EUT shall not exhibit any malfunction, degradation of performance, or deviation from specified indications, beyond the tolerances indicated in the individual equipment or subsystem specification, when subjected to a test signal with voltage levels as specified in Figure CS114. The requirement is also met when the power source is adjusted to dissipate the power level shown in Figure CS114 and the EUT is not susceptible.

5-5.2 Test Procedure

The CS114 test is used to verify the ability of the EUT to withstand RF signals coupled onto EUT associated cabling

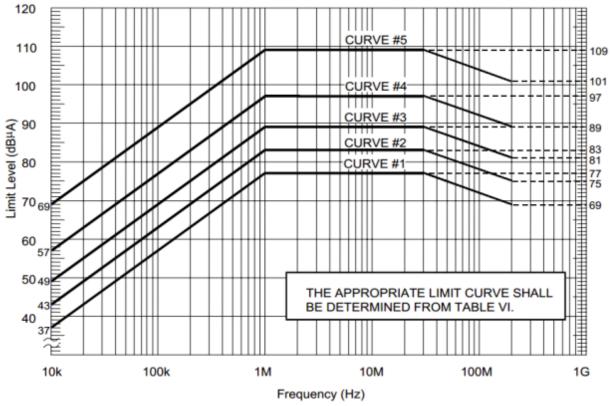
Frequency Range: 10KHz(4 KHz) – 200MHz

Dwell Time: The greater of 3 seconds or EUT response time per frequency

Frequency Step: max 5% (4KHz-1MHz), max 1% (1MHz-30MHz), max 0.1% (30MHz-200MHz)

Unit: Current (dBuA)

Modulation: 1KHz, 50% Duty Cycle, Pulse Modulation



Classification Of Functional Status

All classifications are for the total device/system functional status.

Class A: all functions of a device/system perform as designed during and after exposure to disturbance.

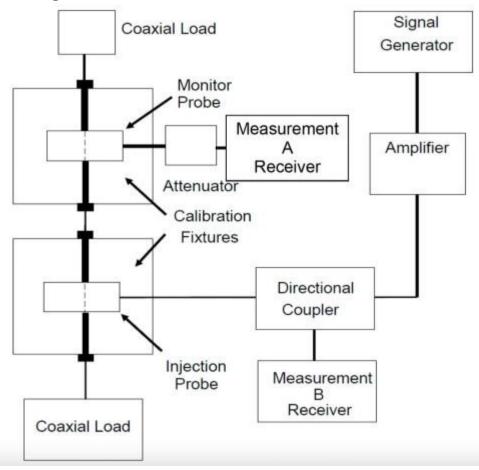
Class B: all functions of a device/system perform as designed during exposure. However, one or more of them can go beyond specified tolerance. All functions return automatically to within normal limits after exposure is removed.

Class C: one or more functions of a device/system do not perform as designed during exposure but return automatically to normal operation after exposure is removed.

Class D: one or more functions of a device/system do not perform as designed during exposure and do not return to normal operation until exposure is removed and the device/system is reset by simple "operator/use" action.

Class E: one or more functions of a device/system do not perform as designed during and after exposure and cannot be returned to proper operation without repairing or replacing the device/system.

5-5.3 Test Configuration

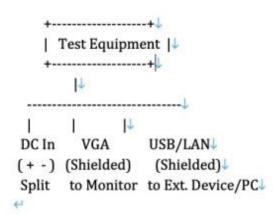


5-5.4 Test Setup of wires in the DC In cable:

All I/O cables are tested whole. The Power cable is tested as a bundle (i.e. all wires) and \circ also with just the + line.

The following diagram illustrates the test setup and the separation of wires in the DC In cable:





5-6 CS115 TEST

5-6.1 Requirements

Perform the Conducted susceptibility, bulk cable injection test in accordance with MIL-STD-461G the following parameters: **impulse excitation**

Limit

The EUT shall not exhibit any malfunction, degradation of performance, or deviation from specified indications, beyond the tolerances indicated in the individual equipment or subsystem specification, when subjected to a test signal with voltage levels as specified in Figure CS115. The requirement is also met when the power source is adjusted to dissipate the power level shown in Figure CS115 and the EUT is not susceptible.

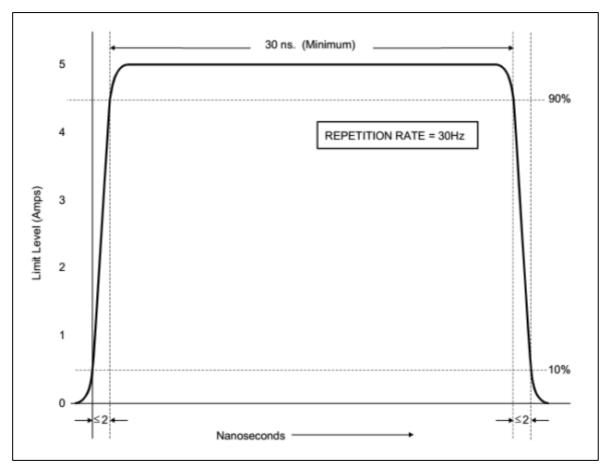
5-6.2 Test Procedure

The CS115 test is used to verify the ability of the EUT to withstand impulse signals coupled onto EUT associated cabling

Frequency Range: Broadband

Unit: Current (A)
Signal: Impulse

Test duration: 1 minute per application



Classification Of Functional Status

All classifications are for the total device/system functional status.

Class A: all functions of a device/system perform as designed during and after exposure to disturbance.

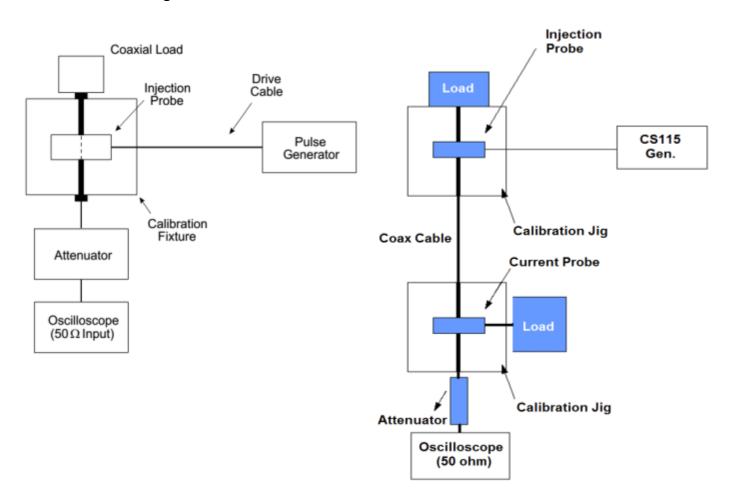
Class B: all functions of a device/system perform as designed during exposure. However, one or more of them can go beyond specified tolerance. All functions return automatically to within normal limits after exposure is removed.

Class C: one or more functions of a device/system do not perform as designed during exposure but return automatically to normal operation after exposure is removed.

Class D: one or more functions of a device/system do not perform as designed during exposure and do not return to normal operation until exposure is removed and the device/system is reset by simple "operator/use" action.

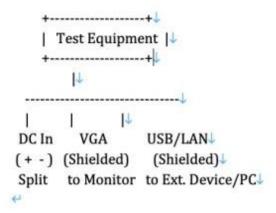
Class E: one or more functions of a device/system do not perform as designed during and after exposure and cannot be returned to proper operation without repairing or replacing the device/system.

5-6.3 Test Configuration



5-6.4 Test Setup of wires in the DC In cable:

The following diagram illustrates the test setup and the separation of wires in the DC In cable:



All I/O cables are tested whole. The Power cable is tested as a bundle (i.e. all wires) and also with just the + line.

5-7 CS116 TEST

5-7.1 Requirements

Perform the Conducted susceptibility, damped sinusoidal transients, cables and power leads test in accordance with MIL-STD-461G the following parameters:10KHz to 100MHz

Limit

The EUT shall not exhibit any malfunction, degradation of performance, or deviation from specified indications, beyond the tolerances indicated in the individual equipment or subsystem specification, when subjected to a test signal with voltage levels as specified in Figure CS116. The requirement is also met when the power source is adjusted to dissipate the power level shown in Figure CS116 and the EUT is not susceptible.

5-7.2 Test Procedure

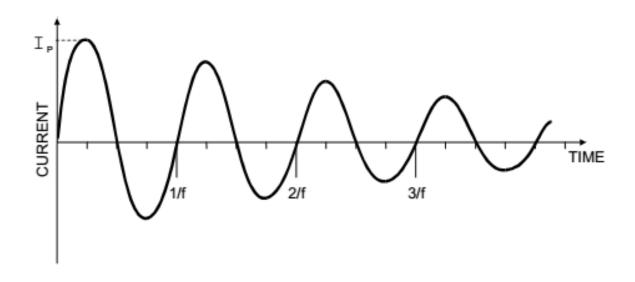
The CS116 test is used to verify the ability of the EUT to withstand damped sinusoidal transients coupled onto EUT associated cables and power leads.

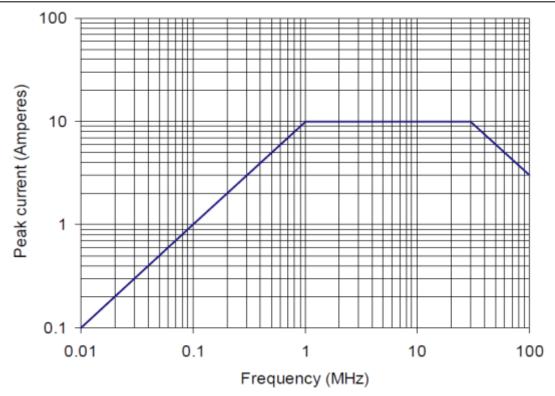
Frequency Range: 10KHz-100MHz

Unit: Current (A)

Interference Signal: Damped Sinusoidal Transients

Test Duration: 5 minutes per application





Test Frequencies: 10 kHz, 100 kHz, 1 MHz, 10 MHz, 30 MHz, 100 MHz as a minimum

Classification Of Functional Status

All classifications are for the total device/system functional status.

Class A: all functions of a device/system perform as designed during and after exposure to disturbance.

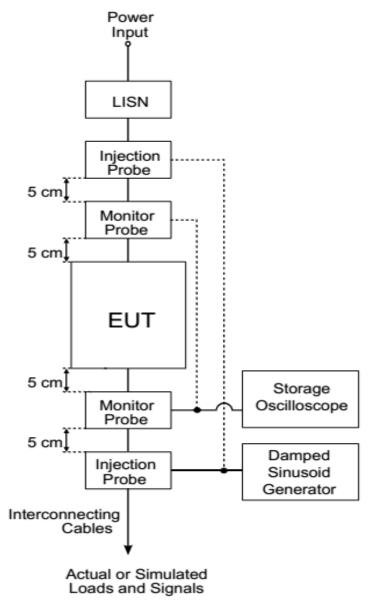
Class B: all functions of a device/system perform as designed during exposure. However, one or more of them can go beyond specified tolerance. All functions return automatically to within normal limits after exposure is removed.

Class C: one or more functions of a device/system do not perform as designed during exposure but return automatically to normal operation after exposure is removed.

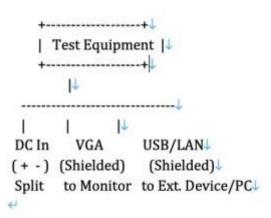
Class D: one or more functions of a device/system do not perform as designed during exposure and do not return to normal operation until exposure is removed and the device/system is reset by simple "operator/use" action.

Class E: one or more functions of a device/system do not perform as designed during and after exposure and cannot be returned to proper operation without repairing or replacing the device/system.

5-7.3 Test Configuration



The following diagram illustrates the test setup and the separation of wires in the DC In Cable:



All I/O cables are tested whole including the Power cable.

5-8 CS118 TEST

5-8.1 Requirements

This requirement is applicable to electrical, electronic, and electromechanical subsystems and equipment that have a man-machine interface.

Limit

The EUT shall not exhibit any malfunction, degradation of performance, or deviation from specified indications, beyond the tolerances indicated in the individual equipment or subsystem specification, when subjected to the values shown in Table while discharging from a 150 picofarads capacitor through a 330 ohm resistor with a circuit inductance not to exceed 5 microhenry. Contact discharge at 8kV is required for conductive surfaces. Air discharge is only required where contact discharge cannot be applied

5-8.2 Test Procedure

The test equipment shall be as follows:

- a. ESD Generator, adjustable from ±2kV to ±15kV (minimum range), for simplified ESD generator characteristics.
- b. ESD network, 150 picofarads (pF) capacitance, 330 ohm discharge resistance.
- c. Contact discharge tip Figure CS118-2
- d. Air discharge tip Figure CS118-2
- e. Electrostatic voltmeter.
- f. Oscilloscope, single event bandwidth ≥ 1 GHz.
- g. ESD current target, input resistance 2 ±5% ohms Figure CS118-3.
- h. Attenuator, 20 dB.
- i. Coaxial cable, 50 ohm impedance, ≤ 1 meter.
- j. Metallic ground plane.
- k. Ionizer or one (1) megohm resistor (1M Ω ±10%).

Level	Test Voltage (kV)	Discharge Method
1	±2	Air
2	± 4	Air
3	±8	Contact/Air
4	± 15	Air

Display Voltage (kV)	First Peak Current, ± 15% (A)	Rise Time (ns)	Current I ₁ , $\pm 30\%$ (A) at $t_1 = 30$ ns	Current I_2 , $\pm 30\%$ (A) at $t_2 = 60$ ns
± 8	30	$0.6 \le t_r \le 1.0$	16	8

Rise time is defined as the time from 10% to 90% of the peak value of the current waveform.

Typical test consists of 5 positive discharges and 5 negative discharges per test point.

TABLE X. ESD generator general specifications.

Parameters	Values
Output voltage, contact discharge mode (see NOTE 1)	At least 2 kV to 8 kV, nominal
Output voltage, air discharge mode (see NOTE 1)	At least 2 kV to 15 kV, nominal
Tolerance of output voltage	±5 %
Polarity of output voltage	Positive and negative
Holding time	≥5 s
Discharge mode of operation	Single discharge (see NOTE 2)

NOTE 1: Open circuit voltage measured at the discharge electrode of the ESD generator. NOTE 2: The generator should be able to generate at the repetition rate of at least 20

discharges per second for exploratory purposes.

MIL-STD-461G

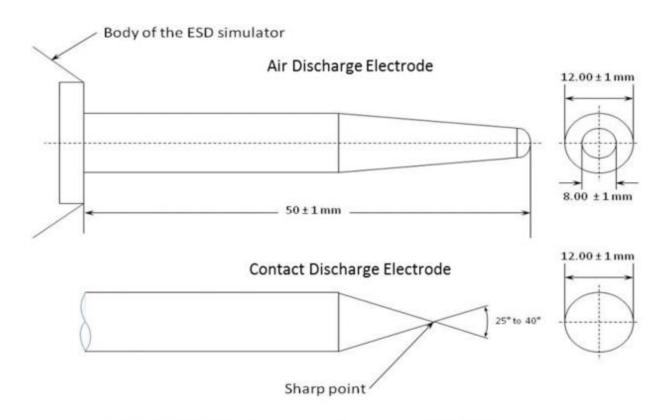


FIGURE CS118-2. Discharge electrodes of the ESD generator.

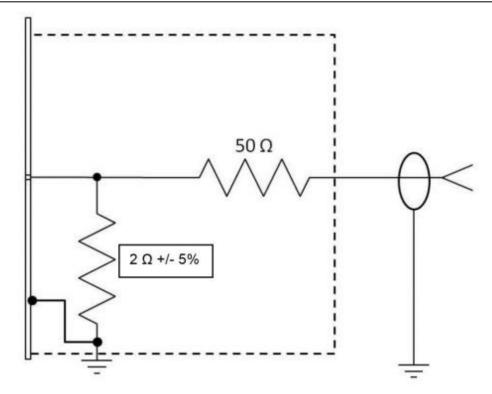


FIGURE CS118-3. Sample ESD current target schematic representation.

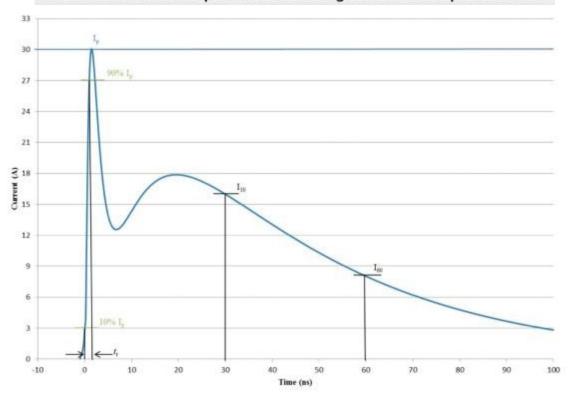
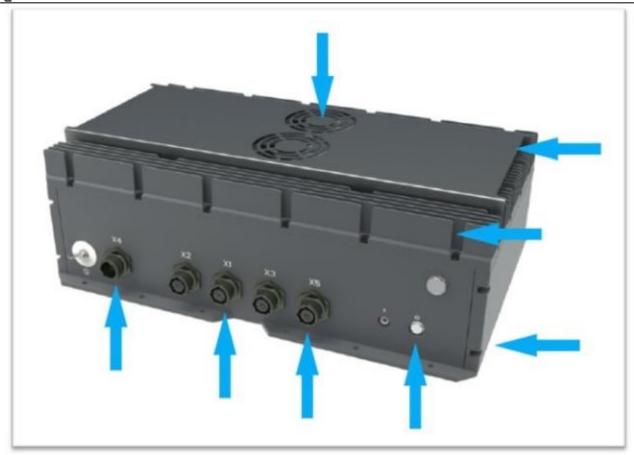


FIGURE CS118-4. Ideal contact discharge current waveform at 8 kV.



Apply five (5) positive discharges and five (5) negative discharges to each EUT test point as discussed in test point selection in 5.16.3.3 (b). (Test Point Selection. The electrostatic discharges shall be applied to those points and surfaces of the EUT which are accessible to the operator/installer during normal use. Test points to be considered shall include the following locations as applicable: any conductive or non-conductive points in the control or keyboard area and any other point of human contact such as switches, knobs, buttons, indicators LEDs, seams slots, grilles, connector shells and other accessible areas. As a minimum, each face shall be included.)